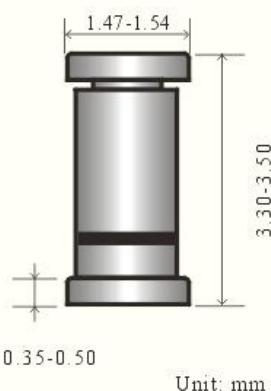


**LL-34 GLASS**

**LL-34(Mini-melf)玻璃封装二极管  
LL-34(Mini-melf) Glass Switching Diode**
**特征 Features**

- 开关速度小于 4.0nS; Fast Switching Device (TRR <4.0 nS)
- 最大功率耗散 500mW; Power Dissipation of 500mW
- 高稳定性和可靠性。High Stability and High Reliability
- 反向漏电流小。Low reverse leakage

**机械数据 Mechanical Data**

- 封装: LL-34 玻璃封装 Case: LL-34 Glass Case
- 极性: 色环端为负极 Polarity: Color band denotes cathode end
- 安装位置: 任意 Mounting Position: Any

**极限值和温度特性(TA = 25°C 除非另有规定)**

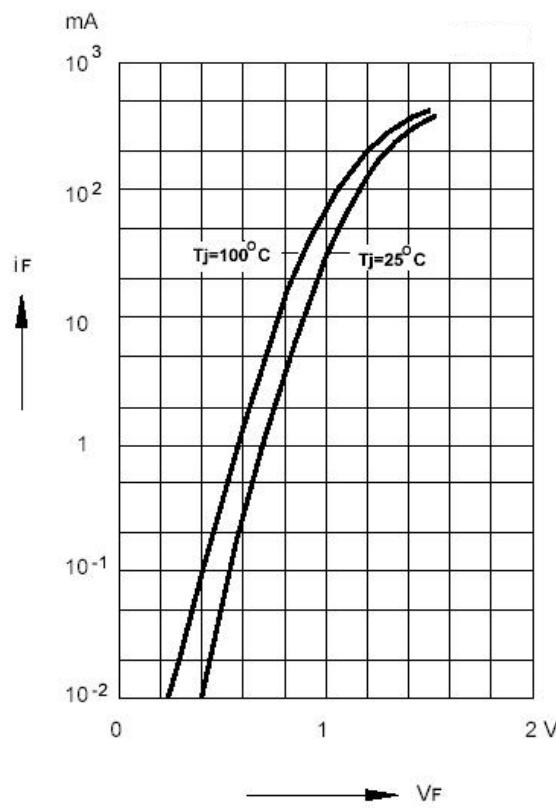
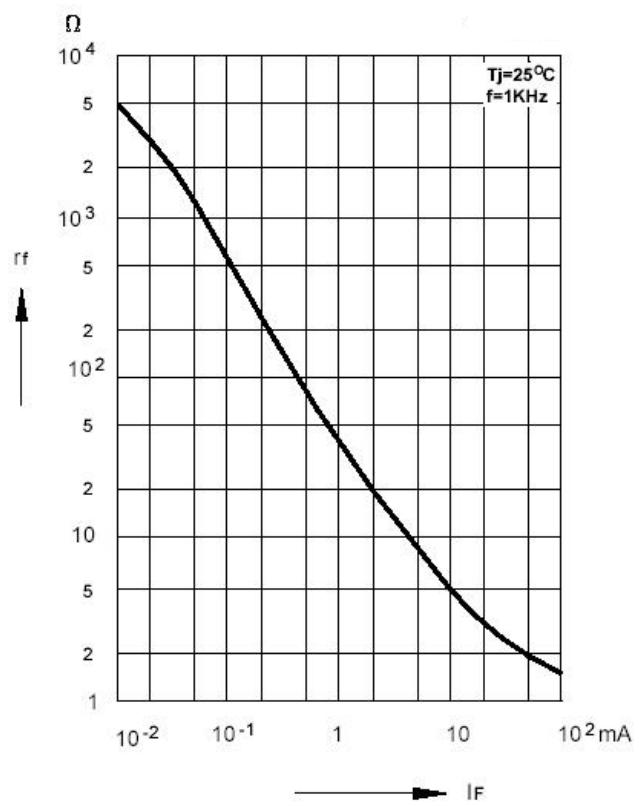
**Maximum Ratings & Thermal Characteristics** (Ratings at 25°C ambient temperature unless otherwise specified.)

参数 Parameters	符号 Symbol	数值 Value	单位 Unit
反向电压 Reverse Voltage	VR	75	V
反向峰值电压 Peak Reverse Voltage	VRM	100	V
功率消耗 Power Dissipation	Pd	500	mW
工作结温 Operating junction temperature	Tj	175	°C
存储温度 Storage temperature range	Ts	-65-+200	°C
反向工作电压 Working Inverse Voltage	WIV	75	V
平均整流电流 Average Rectified Current	Io	150	mA
正向(不重复)电流 Non-repetitive Peak Forward Current	IFM	450	mA
正向(不重复)浪涌电流 Peak Forward Surge Current @tp=1s; TA=25°C	IFSM	2.0	A

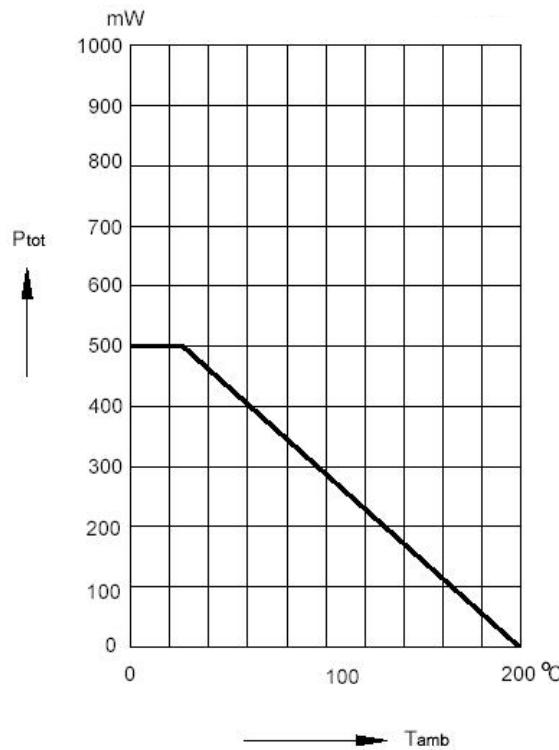
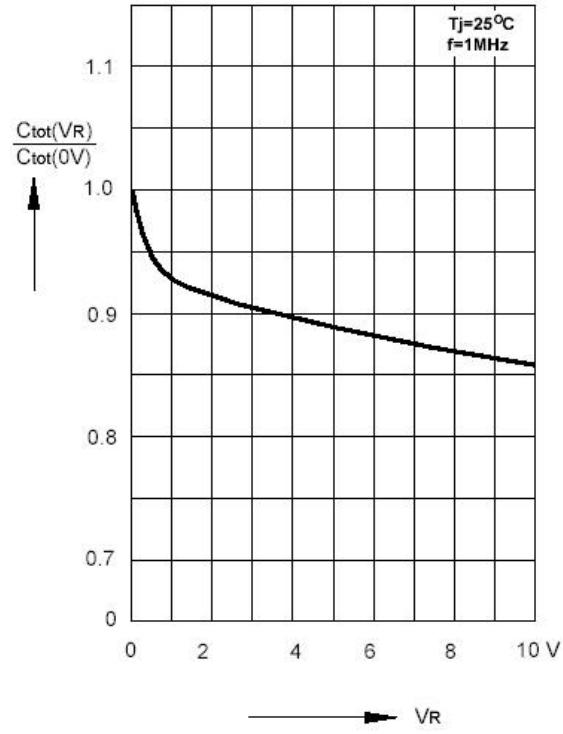
Valid provided that electrodes are kept at ambient temperature.

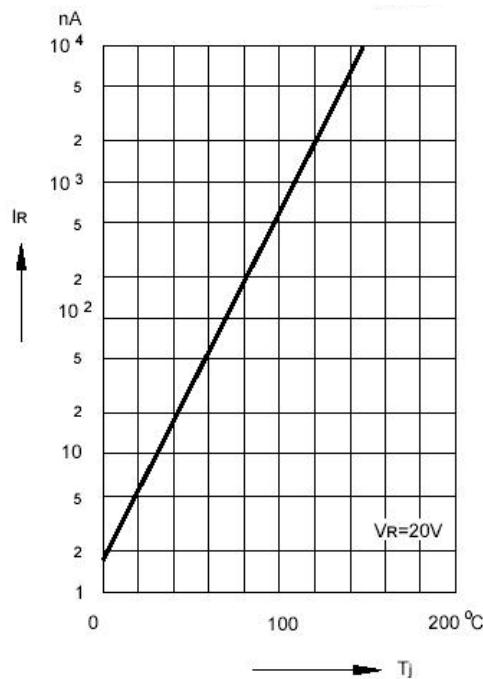
**电特性 Electrical Characteristics** (Ratings at 25°C ambient temperature unless otherwise specified).

符号 Symbols	参数 Parameter	测试条件 Test Condition	界限 Limits		单位 Unit
			Min	Max	
<b>Bv</b>	反向击穿电压 Breakdown Voltage	IR=100uA IR=5uA	100 75		V
		VR=20V VR=75	---	25 5	
<b>IR</b>	反向漏电电流 Reverse Leakage Current	IF=10mA	---	1	nA uA
		RL=100Ω IRR=1mA	---	4	
<b>VF</b>	正向电压 Forward Voltage	IF= 10mA, IR=1.0mA	---	4	nS
		VR=0V, f=1MHZ	---	4	
<b>TRR</b>	反向恢复时间 Reverse Recovery Time	RL=100Ω IRR=1mA	---	4	pF
			---	4	
<b>C</b>	结电容 Capacitance		---	4	pF
			---	4	

**Forward characteristics**

**Dynamic forward resistance versus forward current**

**Admissible power dissipation versus ambient temperature**

Valid provided that leads at a distance of 8 mm from case are kept at ambient temperature


**Relative capacitance versus reverse voltage**


**Leakage current versus junction temperature**

**Admissible repetitive peak forward current versus pulse duration**

Valid provided that leads at a distance of 8 mm from case are kept at ambient temperature

